Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: http://www.renesas.com

April 1st, 2010 Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (http://www.renesas.com)

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DATA SHEET



MOS FIELD EFFECT TRANSISTOR Phase-out/Discontinued 2SJ493

SWITCHING P-CHANNEL POWER MOS FET INDUSTRIAL USE

DESCRIPTION

This product is P-Channel MOS Field Effect Transistor designed for high current switching applications.

ORDERING INFORMATION

PART NUMBER	PACKAGE			
2SJ493	Isolated TO-220			

FEATURES

- Super low on-state resistance $R_{DS(on)1} = 100 \text{ m}\Omega \text{ (MAX.)} \text{ (VGs} = -10 \text{ V, ID} = -8 \text{ A)}$ $R_{DS(on)2} = 185 \text{ m}\Omega \text{ (MAX.)} \text{ (VGs} = -4 \text{ V, ID} = -8 \text{ A)}$
- Low Ciss: Ciss = 1210 pF (TYP.)
- Built-in gate protection diode

ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

Drain to Source Voltage (Vgs = 0 V)	VDSS	-60	V
Gate to Source Voltage (VDS = 0 V)	VGSS(AC)	∓ 20	V
Gate to Source Voltage (VDS = 0 V) ^{Note1}	VGSS(DC)	-20, 0	V
Drain Current (DC)	ID(DC)	∓ 16	А
Drain Current (pulse) Note2	D(pulse)	∓ 64	А
Total Power Dissipation (Tc = 25°C)	Pτ	30	W
Total Power Dissipation (TA = 25°C)	P⊤	2.0	W
Channel Temperature	Tch	150	°C
Storage Temperature	Tstg	–55 to +150	°C
Single Avalanche Current Note3	las	-16	А
Single Avalanche Energy Note3	Eas	25.6	mJ

Notes 1. f = 20 kHz, Duty Cycle $\leq 10\%$ (+Side)

- **2.** PW \leq 10 μ s, Duty Cycle \leq 1 %
- 3. Starting T_{ch} = 25 °C, R_A = 25 Ω , V_{GS} = -20 V \rightarrow 0

THERMAL RESISTANCE

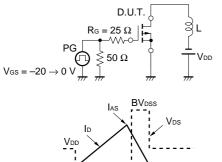
Channel to Case	Rth(ch-C)	4.17	°C/W
Channel to Ambient	Rth(ch-A)	62.5	°C/W

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ELECTRICAL CHARACTERISTICS (TA = 25 °C)

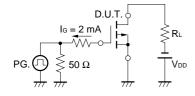
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Drain to Source On-state Resistance	RDS(on)1	$V_{GS} = -10 \text{ V}, \text{ Id} = -8 \text{ A}$		70	100	mΩ
	RDS(on)2	$V_{GS} = -4 V, I_{D} = -8 A$		120	185	mΩ
Gate to Source Cut-off Voltage	V _{GS(off)}	$V_{DS} = -10 V$, $I_{D} = -1 mA$	-1.0	-1.5	-2.0	V
Forward Transfer Admittance	y _{fs}	$V_{DS} = -10 \text{ V}, \text{ Id} = -8 \text{ A}$	5.0	11		S
Drain Leakage Current	IDSS	$V_{DS} = -60 V, V_{GS} = 0 V$			-10	μA
Gate to Source Leakage Current	lgss	$V_{GS} = \mp 20 V$, $V_{DS} = 0 V$			∓ 10	μA
Input Capacitance	Ciss	$V_{DS} = -10 V$		1210		pF
Output Capacitance	Coss	Vgs = 0 V		520		pF
Reverse Transfer Capacitance	Crss	f = 1 MHz		180		pF
Turn-on Delay Time	td(on)	ID = -8 A		15		ns
Rise Time	tr	$V_{GS(on)} = -10 V$		130		ns
Turn-off Delay Time	$t_{d(off)}$	$V_{DD} = -30 V$		95		ns
Fall Time	tr	$R_G = 10 \Omega$		80		ns
Total Gate Charge	QG	ID = -16 A		42		nC
Gate to Source Charge	Q _{GS}	$V_{DD} = -48 V$		8.0		nC
Gate to Drain Charge	Qgd	$V_{GS} = -10 V$		10		nC
Body Diode Forward Voltage	VF(S-D)	IF = 16 A, VGS = 0 V		1.0		V
Reverse Recovery Time	trr	IF = 16 A, VGs = 0 V		120		ns
Reverse Recovery Charge	Qrr	di/dt = 50 A/ μ s		230		nC

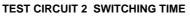
TEST CIRCUIT 1 AVALANCHE CAPABILITY

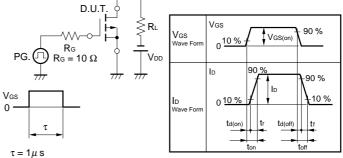


Starting Tch

TEST CIRCUIT 3 GATE CHARGE



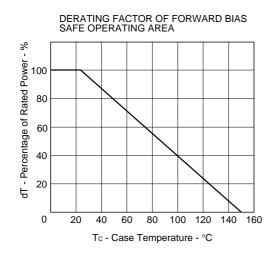




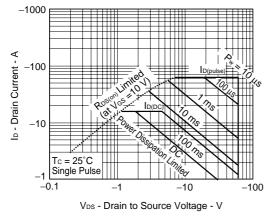
Duty Cycle $\leq 1 \%$



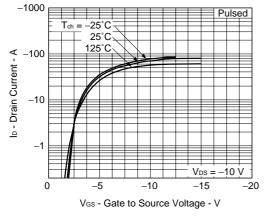
TYPICAL CHARACTERISTICS (TA = 25 °C)

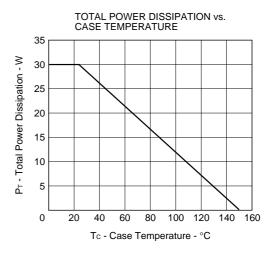




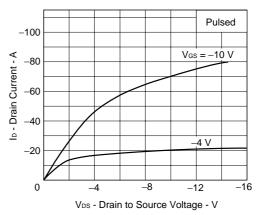


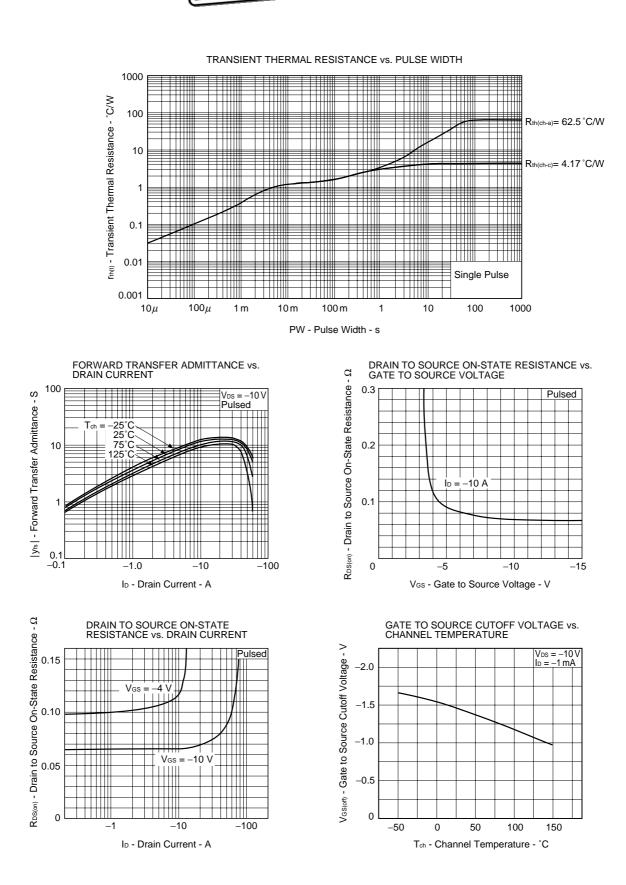






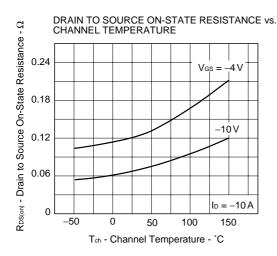


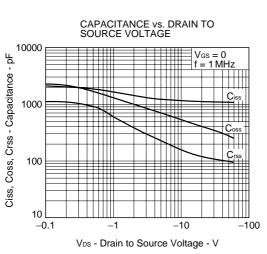


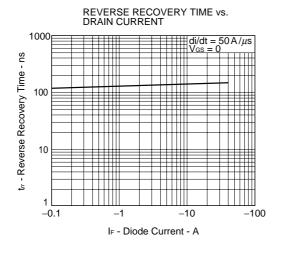


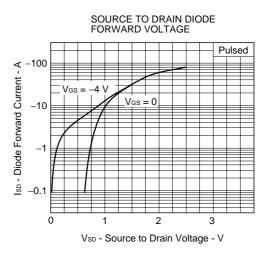
NEC

Phase-out/Discontinued

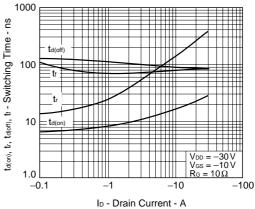


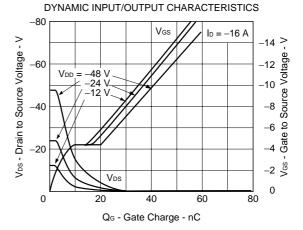




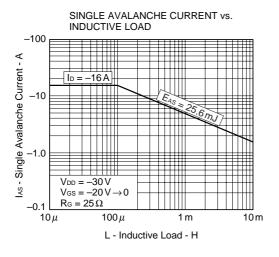


SWITCHING CHARACTERISTICS

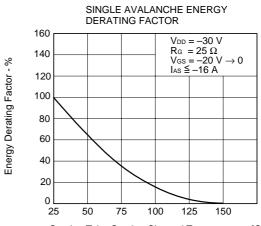




Data Sheet D11265EJ3V0DS00



NEC

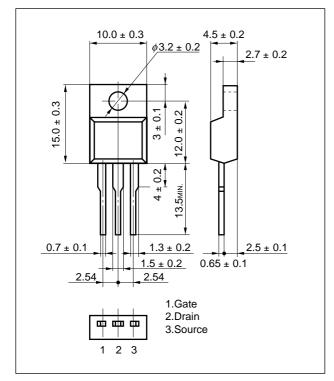


Starting Tch - Starting Channel Temperature - °C

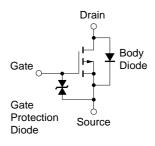
Data Sheet D11265EJ3V0DS00

PACKAGE DRAWING (Unit: mm)

Isolated TO-220(MP-45F)



EQUIVALENT CIRCUIT



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device. No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

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- Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots
- Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)
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